## ELECTRICAL CHARACTERISTICS ( $\rm T_{_{A}}$ = 25°C Unless otherwise noted )

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage $(V_F)$ Reverse Current $(I_R)$		1.2	1.5 10	V μA	$I_{\rm F} = 20 \text{mA}$ $V_{\rm R} = 6 \text{V}$
Output	Peak Off-state Current ( $I_{DRM}$ ) Peak Blocking Voltage ( $V_{DRM}$ ) On-state Voltage ( $V_{TM}$ )	250		500 3.0	nA V V	$V_{DRM} = 250 V \text{ (note 1)}$ $I_{DRM} = 500 \text{nA}$ $I_{TM} = 100 \text{mA (peak)}$
	Critical rate of rise of off-state Voltage ( dv/dt )	600	1500		V/µs	
Coupled	Input Current to Trigger ( I <sub>FT</sub> )(note 2 )  MOC3030  MOC3031  MOC3032  MOC3033			30 15 10 5	mA mA mA	$V_{TM} = 3V \text{ (note 2)}$
	Holding Current , either direction ( $\rm I_{\rm H}$ ) Input to Output Isolation Voltage $\rm V_{\rm ISO}$	5300 7500	400		$\begin{array}{c} \mu A \\ V_{\text{RMS}} \\ V_{\text{PK}} \end{array}$	See note 3 See note 3
Zero Crossing Charact- -eristic	Inhibit Voltage (V <sub>IH</sub> )			20	V	I <sub>F</sub> = Rated I <sub>FT</sub> MT1-MT2 Voltage above which device
	Leakage in Inhibited State ( $I_S$ )			500	μΑ	will not trigger $I_F = Rated I_{FT}$ $V_{DRM} = 250V \text{ off-state}$

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Note 1. Test voltage must be applied within dv/dt rating. Note 2. Guaranteed to trigger at an  $\rm\,I_F$  value less than or equal to max.  $\rm\,I_{FT}$ , recommended  $\rm\,I_F$  lies between Rated  $\rm\,I_{FT}$  and absolute max.  $\rm\,I_F$ . Note 3. Measured with input leads shorted together and output leads shorted together.